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| APPLICATION NO.  | FILING DATE     | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO.     | CONFIRMATION NO. |  |
|--|-----------------|----------------------|-------------------------|------------------|--|
| 09/944,186   | 09/04/2001      | Atsushi Yamaguchi    | PF-2871                 | 1202             |  |
| 466  | 7590 03/05/2003 |                      |                         |                  |  |
| YOUNG & THOMPSON                                       |                 |                      | EXAMINER                |                  |  |
| 745 SOUTH 23RD STREET 2ND FLOOR<br>ARLINGTON, VA 22202 |                 | R                    | HU, SHO                 | HU, SHOUXIANG    |  |
|  |                 |                      | ART UNIT                | PAPER NUMBER     |  |
|  |                 |                      | 2811                    |                  |  |
|  | •               |                      | DATE MAILED: 03/05/2003 |                  |  |

Please find below and/or attached an Office communication concerning this application or proceeding.

| · · · · · · · · · · · · · · · · · · ·  | Ammlication 81-  |  |
|--|--|--|
|  | Application No.  | Applicant(s)   |
| Office Action Summany  | 09/944,186   | YAMAGUCHI ET AL.   |
| Office Action Summary  | Examiner   | Art Unit   |
|  | Shouxiang Hu   | 2811   |
| The MAILING DATE of this communication Period for Reply  | app ars on the cov r sheet w   | ith the correspondenc address  |
| A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION  - Extensions of time may be available under the provisions of 37 CFI after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, and a lift NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by standard patent term adjustment. See 37 CFR 1.704(b).  Status | N. R 1.136(a). In no event, however, may a reply within the statutory minimum of thir eriod will apply and will expire SIX (6) MON tatute, cause the application to become A | reply be timely filed  ty (30) days will be considered timely.  NTHS from the mailing date of this communication.  BANDONED (35 U.S.C. § 133). |
| <u> </u>   | 03 January 2002  |  |
| · · · · · · · · · · · · · · · · · · ·  |  |  |
| 2a) This action is <b>FINAL</b> . 2b)  | This action is non-final.  |  |
| 3) Since this application is in condition for all closed in accordance with the practice uno Disposition of Claims   |  |  |
| 4) Claim(s) 1-120 is/are pending in the application  | cation.  | ,  |
| 4a) Of the above claim(s) is/are with  | drawn from consideration.  |  |
| 5) Claim(s) is/are allowed.  |  |  |
| 6) Claim(s) is/are rejected.   |  |  |
| 7) Claim(s) is/are objected to.  |  |  |
| 8) Claim(s) <u>1-120</u> are subject to restriction and <b>Application Papers</b>  | d/or election requirement.   |  |
| 9) The specification is objected to by the Exam  | niner.   |  |
| 10) ☐ The drawing(s) filed on is/are: a) ☐ a   |  | he Examiner.   |
| Applicant may not request that any objection to  |  |  |
| 11) The proposed drawing correction filed on   | is: a)□ approved b)□ d   | isapproved by the Examiner.  |
| If approved, corrected drawings are required in  | n reply to this Office action.   |  |
| 12) The oath or declaration is objected to by the  | Examiner.  |  |
| Priority under 35 U.S.C. §§ 119 and 120  |  |  |
| 13) Acknowledgment is made of a claim for fore   | eign priority under 35 U.S.C. §  | § 119(a)-(d) or (f).   |
| a)⊠ All b)□ Some * c)□ None of:  |  |  |
| 1. Certified copies of the priority docum  | ents have been received.   |  |
| 2. Certified copies of the priority docum  |  | pplication No  |
| 3. Copies of the certified copies of the papplication from the International  * See the attached detailed Office action for a  | priority documents have been Bureau (PCT Rule 17.2(a)).  | received in this National Stage  |
| 14) Acknowledgment is made of a claim for dome   | <u>·</u>   |  |
| a) The translation of the foreign language 15) Acknowledgment is made of a claim for dom   | provisional application has be   | een received.  |
| Attachment(s)  | -  |  |
| Notice of References Cited (PTO-892)  Notice of Draftsperson's Patent Drawing Review (PTO-948)  Information Disclosure Statement(s) (PTO-1449) Paper No(s  | 5) Notice of I   | Summary (PTO-413) Paper No(s)  Informal Patent Application (PTO-152)   |
| 6. Patent and Trademark Office FO-326 (Rev. 04-01) Office  | e Action Summary   | Part of Paper No. 6  |

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## **DETAILED ACTION**

## Election/Restrictions

This application contains claims 1-120 directed to the following patentably distinct species of the claimed invention:

Species 1 (claims 1-10), a semiconductor device, wherein a threshold mode gain of each of the at least quantum well is not more than 12 cm<sup>-1</sup>, and wherein a standard deviation of a microscopic fluctuation in a band gap energy of said at least luminescent layer is in the range of 75 meV to 200 meV.

Species 2 (claims 11-20), a semiconductor device, wherein a threshold mode gain of each of said at least quantum well is not more than 12 cm<sup>-1</sup>, and wherein a differential gain "dg/dn" of the at least active layer satisfies  $0.5 \times 10^{-20}$  (m<sup>2</sup>)  $\leq$  dg/dn  $\leq$  0.7  $\times 10^{-20}$  (m<sup>2</sup>).

Species 3 (claims 21-30), a semiconductor device, wherein an internal loss " $\alpha_i$ " (cm<sup>-1</sup>) which satisfies:  $\alpha_i \le 12xn - \alpha_m$  (cm<sup>-1</sup>), where  $\alpha_m$  is a mirror loss, and "n" is a number of said at least quantum well, and wherein a standard deviation of a microscopic fluctuation in a band gap energy of said at least luminescent layer is in the range of 75 meV to 200 meV.

Species 4 (claims 31-40), a semiconductor device, wherein an internal loss " $\alpha_i$ " (cm<sup>-1</sup>) which satisfies:  $\alpha_i \leq 12xn - \alpha_m$  (cm<sup>-1</sup>), where  $\alpha_m$  is a mirror loss, and "n" is a number of said at least quantum well, and wherein a differential gain "dg/dn" of said at least active layer satisfies  $0.5x10^{-20}$  (m<sup>2</sup>)  $\leq$  dg/dn  $\leq$  0.7  $x10^{-20}$  (m<sup>2</sup>).

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Species 5 (claims 41-50), a semiconductor device, wherein a slope efficiency "S" (W/A) which satisfies:  $S \geq 3x \{\alpha_m / (12xn)\} \times [\{(1-R_1) \times \text{squareroot} (R_2)\} / \{(1-\text{squareroot} (R_1R_2) \times (\text{squareroot} (R_1) + \text{squareroot} (R_2)\}], \text{ where } R_1 \text{ is a first reflectance of a first cavity facet, from which a light is emitted, } R_2 \text{ is a second reflectance of a second cavity facet opposite to the first cavity facet, } \alpha_m \text{ is a mirror loss, and "n" is a number of the at least quantum well, and wherein a standard deviation of a microscopic fluctuation in a band gap energy of said at least luminescent layer is in the range of 75 meV to 200 meV.$ 

Species 6 (claims 51-60), a semiconductor device, wherein a slope efficiency "S" (W/A) which satisfies:  $S \ge 3x \{\alpha_m/(12xn)\} x [\{(1-R_1) x \text{ squareroot } (R_2)\} / \{(1-\text{ squareroot } (R_1R_2) x \text{ (squareroot } (R_1) + \text{ squareroot } (R_2)\}], \text{ where } R_1 \text{ is a first reflectance of a first cavity facet, from which a light is emitted, } R_2 \text{ is a second reflectance of a second cavity facet opposite to the first cavity facet, } \alpha_m \text{ is a mirror loss, and "n" is a number of the at least quantum well, and wherein a differential gain "dg/dn" of the at least active layer satisfies <math>0.5x10^{-20} \text{ (m}^2) \le \text{dg/dn} \le 0.7 \times 10^{-20} \text{ (m}^2)$ .

Species 7 (claims 61-70), a semiconductor device, wherein a threshold mode gain of each of said at least quantum well is more than 12 cm<sup>-1</sup>, and wherein a standard deviation of a microscopic fluctuation in a band gap energy of said at least luminescent layer is not more than of 40 meV.

Species 8 (claims 71-80), a semiconductor device, wherein a threshold mode gain of each of said at least quantum well is more than 12 cm<sup>-1</sup>, and wherein a differential gain "dg/dn" of said at least active layer satisfies dg/dn  $\geq$ 1.0 x 10<sup>-20</sup> (m<sup>2</sup>).

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Species 9 (claims 81-90), a semiconductor device, wherein an internal loss " $\alpha_i$ " (cm<sup>-1</sup>) which satisfies:  $\alpha_i > 12xn - \alpha_m$  (cm<sup>-1</sup>), where  $\alpha_m$  is a mirror loss, and "n" is a number of said at least quantum well, and wherein a standard deviation of a microscopic fluctuation in a band gap energy of said at least luminescent layer is not more than of 40 meV.

Species 10 (claims 91-100), a semiconductor device, wherein an internal loss " $\alpha_i$ " (cm<sup>-1</sup>) which satisfies:  $\alpha_i > 12 \text{xn} - \alpha_m (\text{cm}^{-1})$ , where  $\alpha_m$  is a mirror loss, and "n" is a number of said at least quantum well, and wherein a standard deviation of a microscopic fluctuation in a band gap energy of said at least luminescent layer is not more than of 40 meV, and wherein a differential gain "dg/dn" of said at least active layer satisfies dg/dn  $\geq 1.0 \text{ x} 10^{-20} \text{ (m}^2$ ).

Species 11 (claims 101-120), a semiconductor device, wherein a slope efficiency "S" (W/A) which satisfies:  $S < 3x \{\alpha_m/(12xn)\} \times [\{(1-R_1) \times \text{squareroot} (R_2)\} / \{(1-squareroot) \times (R_1R_2) \times (\text{squareroot} (R_1) + \text{squareroot} (R_2)\}], \text{ where } R_1 \text{ is a first reflectance of a first cavity facet, from which a light is emitted, } R_2 \text{ is a second reflectance of a second cavity facet opposite to the first cavity facet, } \alpha_m \text{ is a mirror loss, } \text{ and "n" is a number of the at least quantum well, } \text{ and wherein a standard deviation of a microscopic fluctuation in a band gap energy of said at least luminescent layer is not more than of 40 meV.}$ 

Applicant is required under 35 U.S.C. 121 to elect a single disclosed species for prosecution on the merits to which the claims shall be restricted if no generic claim is finally held to be allowable. Currently, none is generic.

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Applicant is advised that a reply to this requirement must include an identification of the species that is elected consonant with this requirement, and a listing of all claims readable thereon, including any claims subsequently added. An argument that a claim is allowable or that all claims are generic is considered nonresponsive unless accompanied by an election.

Upon the allowance of a generic claim, applicant will be entitled to consideration of claims to additional species which are written in dependent form or otherwise include all the limitations of an allowed generic claim as provided by 37 CFR 1.141. If claims are added after the election, applicant must indicate which are readable upon the elected species. MPEP § 809.02(a).

Should applicant traverse on the ground that the species are not patentably distinct, applicant should submit evidence or identify such evidence now of record showing the species to be obvious variants or clearly admit on the record that this is the case. In either instance, if the examiner finds one of the inventions unpatentable over the prior art, the evidence or admission may be used in a rejection under 35 U.S.C. 103(a) of the other invention.

Applicant is advised that the reply to this requirement to be complete must include an election of the invention to be examined even though the requirement be traversed (37 CFR 1.143).

Applicant is reminded that upon the cancellation of claims to a non-elected invention, the inventorship must be amended in compliance with 37 CFR 1.48(b) if one or more of the currently named inventors is no longer an inventor of at least one claim

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remaining in the application. Any amendment of inventorship must be accompanied by

a petition under 37 CFR 1.48(b) and by the fee required under 37 CFR 1.17(I).

Conclusion

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Shouxiang Hu whose telephone number is (703) 306-

5729. The examiner can normally be reached on Monday through Thursday, 7:30 AM

to 6:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Tom Thomas can be reached on (703) 308-2772. The fax phone numbers

for the organization where this application or proceeding is assigned are (703) 872-9318

for regular communications and (703) 872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is (703) 308-

0956.

SH

March 4, 2003

Shouxiang Hu Patent Examiner

TC2800

Shousanoghu